

捷多邦,专业PCB打样工厂,24小时加急出货

HMC-MDB218

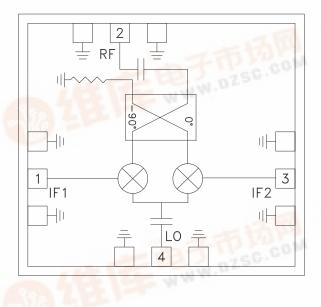
GaAs MMIC SUB-HARMONIC IRM MIXER, 54 - 64 GHz

Typical Applications

This HMC-MDB218 is ideal for:

- Short-Haul / High Capacity Radios
- SATCOM
- Military Radar, ECM & EW
- Sensors
- Test & Measurement Equipment

Functional Diagram



Features

Wide IF Bandwidth: DC - 3 GHz RF Frequency: 54 to 64 GHz LO Frequency: 27 to 32 GHz High Image Rejection: 30 dB Passive; No DC Bias Required Die Size: 1.54 x 1.41 x 0.1 mm

General Description

The HMC-MDB218 is a sub-harmonically pumped (x2) MMIC Mixer which can be used as either an image reject mixer (IRM) or a single sideband upconverter. This passive MMIC mixer is fabricated with GaAs Heterojunction Bipolar Transistor (HBT) Shottky diode technology. For downconversion applications, an external quadrature hybrid can be used to select the desired sideband while rejecting image signals. All bond pads and the die backside are Ti/Au metallized and the Shottky devices are fully passivated for reliable operation. The HMC-MDB218 Sub Harmonic IRM is compatible with conventional die attach methods, as well as thermocompression and thermosonic wire bonding, making it ideal for MCM and hybrid microcircuit applications. All data shown herein is measured with the chip in a 50 Ohm environment and contacted with RF probes.



Electrical Specifications^{*}, $T_A = 25 \text{ °C}$, IF = 1 GHz, LO = +10 dBm

Parameter	Min.	Тур.	Max.	Units
Frequency Range, RF	1711	54 - 64		GHz
Frequency Range, LO	and a	27 - 32		GHz
Frequency Range, IF	CO.	DC - 3		GHz
Conversion Loss		12.5	14	dB
1 dB Compression (Input)		-2		dBm
Image Rejection		30		dB
LO to RF Isolation		30		dB
LO to IF Isolation		30		dB
IP3 (Input)		7		dBm
Amplitude Balance		0.3		dB
Phase Balance		1		Deg

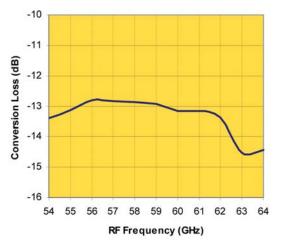
Unless otherwise indicated, all measurements are from probed die

For price delivery and to place orders, please contact Hittite Microwave Corporation:

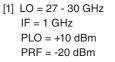


HMC-MDB218

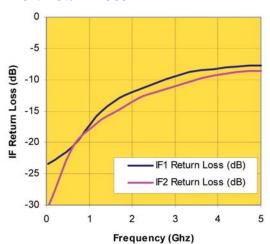
GaAs MMIC SUB-HARMONIC IRM MIXER, 54 - 64 GHz



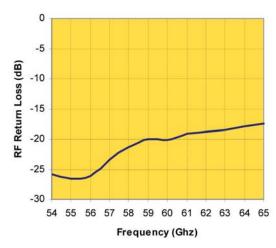
Downconverter Conversion Loss [1]



IF Port Return Loss [2]



RF Port Return Loss^[2]



[2] LO = 29.5 GHz, PLO = 10 dBm

Note 1: Measured Performance Characteristics ($T_{OP} = 25^{\circ}C$)

Note 2: Single side band measurement without 90° hybrid, and second IF port terminated.



HMC-MDB218

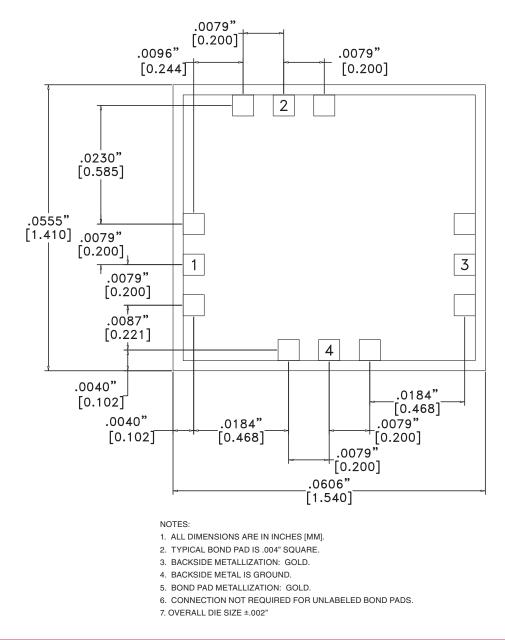
GaAs MMIC SUB-HARMONIC IRM MIXER, 54 - 64 GHz

Absolute Maximum Ratings

LO Drive	16 dBm	
Storage Temperature	-65 °C to 150 °C	
Operating Temperature	-55 °C to 85 °C	



Outline Drawing



For price, delivery, and to place orders, please contact Hittite Microwave Corporation:



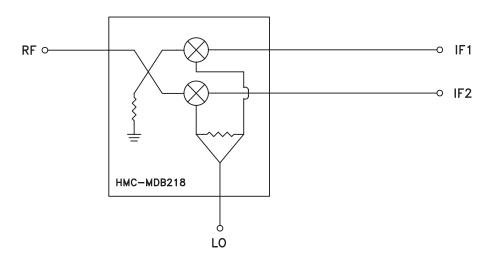
HMC-MDB218

GaAs MMIC SUB-HARMONIC IRM MIXER, 54 - 64 GHz

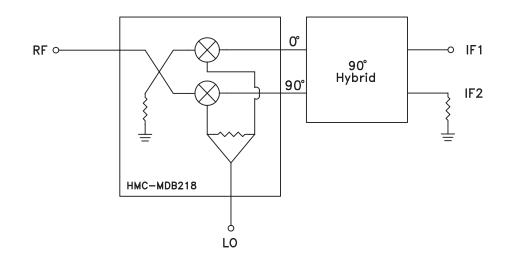
Application Circuits

Application circuit 1 shows the mixer equivalent circuit. Application Circuit 2 depicts the mixer with a 90° hybrid used to achieve signal image rejection. All RF parameters are specified with an ideal 90° hybrid on IF output ports. Conversion loss is measured (on wafer) at IF1 and/or IF2 (Application Circuit 1) with the second IF port terminated into 50 ohms. Three dB is then added to compensate for an ideal hybrid. The IP3 is stated as an input IP3 number and is obtained via a two-tone measurement.

Application Circuit 1







For price, delivery, and to place orders, please contact Hittite Microwave Corporation: